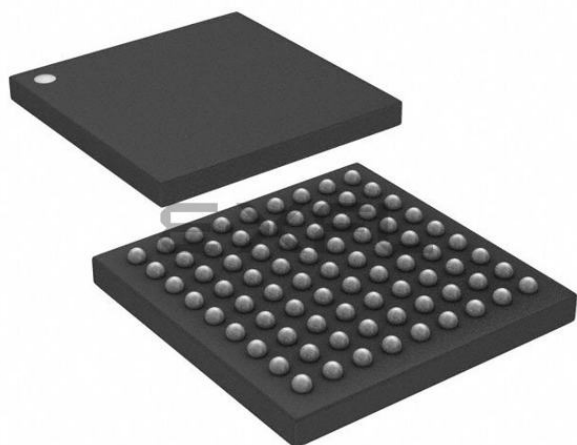




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Understanding Embedded - FPGAs (Field Programmable Gate Array)

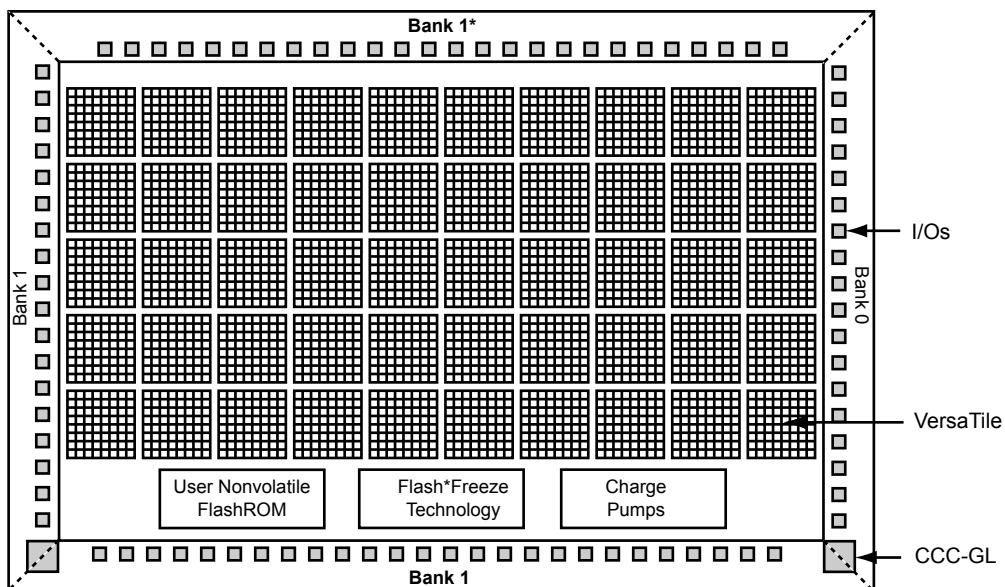
Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details

Product Status	Obsolete
Number of LABs/CLBs	-
Number of Logic Elements/Cells	1536
Total RAM Bits	18432
Number of I/O	60
Number of Gates	60000
Voltage - Supply	1.14V ~ 1.575V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	81-WFBGA, CSBGA
Supplier Device Package	81-CSP (5x5)
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/agln060v2-zcsg81i



Note: *Bank 0 for the AGLN030 device

Figure 1-1 • IGLOO Device Architecture Overview with Two I/O Banks and No RAM (AGLN010 and AGLN030)

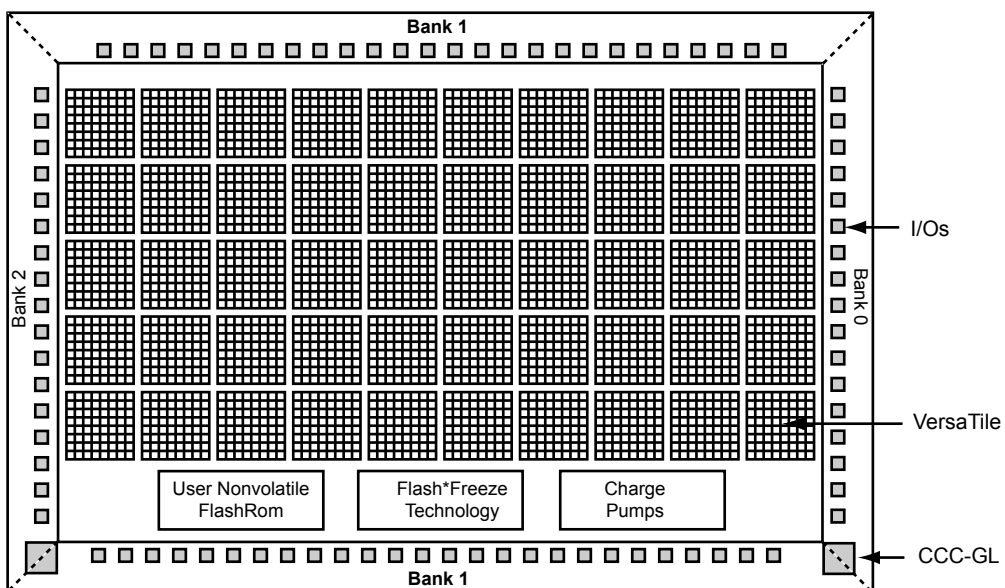


Figure 1-2 • IGLOO Device Architecture Overview with Three I/O Banks and No RAM (AGLN015 and AGLN020)

6. Click **OK** to return to the FlashPoint – Programming File Generator window.

Note: I/O States During programming are saved to the ADB and resulting programming files after completing programming file generation.

Table 2-2 • Recommended Operating Conditions ¹

Symbol	Parameter		Extended Commercial	Industrial	Units
T _J	Junction temperature		–20 to + 85 ²	–40 to +100 ²	°C
VCC	1.5 V DC core supply voltage ³		1.425 to 1.575	1.425 to 1.575	V
	1.2 V–1.5 V wide range core voltage ^{4,5}		1.14 to 1.575	1.14 to 1.575	V
VJTAG	JTAG DC voltage		1.4 to 3.6	1.4 to 3.6	V
VPUMP ⁶	Programming voltage	Programming mode	3.15 to 3.45	3.15 to 3.45	V
		Operation	0 to 3.6	0 to 3.6	V
VCCPLL ⁷	Analog power supply (PLL)	1.5 V DC core supply voltage ³	1.425 to 1.575	1.425 to 1.575	V
		1.2 V–1.5 V wide range core supply voltage ⁴	1.14 to 1.575	1.14 to 1.575	V
VCCI and VMV ^{8,9}	1.2 V DC supply voltage ⁴		1.14 to 1.26	1.14 to 1.26	V
	1.2 V DC wide range supply voltage ⁴		1.14 to 1.575	1.14 to 1.575	V
	1.5 V DC supply voltage		1.425 to 1.575	1.425 to 1.575	V
	1.8 V DC supply voltage		1.7 to 1.9	1.7 to 1.9	V
	2.5 V DC supply voltage		2.3 to 2.7	2.3 to 2.7	V
	3.3 V DC supply voltage		3.0 to 3.6	3.0 to 3.6	V
	3.3 V DC wide range supply voltage ¹⁰		2.7 to 3.6	2.7 to 3.6	V

Notes:

1. All parameters representing voltages are measured with respect to GND unless otherwise specified.
2. Default Junction Temperature Range in the Libero SoC software is set to 0°C to +70°C for commercial, and –40°C to +85°C for industrial. To ensure targeted reliability standards are met across the full range of junction temperatures, Microsemi recommends using custom settings for temperature range before running timing and power analysis tools. For more information regarding custom settings, refer to the New Project Dialog Box in the Libero Online Help.
3. For IGLOO® nano V5 devices
4. For IGLOO nano V2 devices only, operating at VCCI ≥ VCC
5. IGLOO nano V5 devices can be programmed with the VCC core voltage at 1.5 V only. IGLOO nano V2 devices can be programmed with the VCC core voltage at 1.2 V (with FlashPro4 only) or 1.5 V. If you are using FlashPro3 and want to do in-system programming using 1.2 V, please contact the factory.
6. V_{PUMP} can be left floating during operation (not programming mode).
7. VCCPLL pins should be tied to VCC pins. See the "Pin Descriptions" chapter for further information.
8. VMV pins must be connected to the corresponding VCCI pins. See the Pin Descriptions chapter of the IGLOO nano FPGA Fabric User's Guide for further information.
9. The ranges given here are for power supplies only. The recommended input voltage ranges specific to each I/O standard are given in Table 2-21 on page 2-19. VCCI should be at the same voltage within a given I/O bank.
10. 3.3 V wide range is compliant to the JESD8-B specification and supports 3.0 V VCCI operation.

Table 2-3 • Flash Programming Limits – Retention, Storage, and Operating Temperature¹

Product Grade	Programming Cycles	Program Retention (biased/unbiased)	Maximum Storage Temperature T _{STG} (°C) ²	Maximum Operating Junction Temperature T _J (°C) ²
Commercial	500	20 years	110	100
Industrial	500	20 years	110	100

Notes:

1. This is a stress rating only; functional operation at any condition other than those indicated is not implied.
2. These limits apply for program/data retention only. Refer to Table 2-1 on page 2-1 and Table 2-2 for device operating conditions and absolute limits.

Table 2-7 • Temperature and Voltage Derating Factors for Timing Delays (normalized to $T_J = 70^\circ\text{C}$, $V_{CC} = 1.14\text{ V}$)
For IGLOO nano V2, 1.2 V DC Core Supply Voltage

Array Voltage VCC (V)	Junction Temperature ($^\circ\text{C}$)						
	-40°C	-20°C	0°C	25°C	70°C	85°C	100°C
1.14	0.968	0.974	0.979	0.991	1.000	1.006	1.009
1.2	0.863	0.868	0.873	0.884	0.892	0.898	0.901
1.26	0.792	0.797	0.801	0.811	0.819	0.824	0.827

Calculating Power Dissipation

Quiescent Supply Current

Quiescent supply current (I_{DD}) calculation depends on multiple factors, including operating voltages (V_{CC} , V_{CCI} , and V_{JTAG}), operating temperature, system clock frequency, and power mode usage. Microsemi recommends using the Power Calculator and SmartPower software estimation tools to evaluate the projected static and active power based on the user design, power mode usage, operating voltage, and temperature.

Table 2-8 • Power Supply State per Mode

Modes/Power Supplies	Power Supply Configurations				
	VCC	VCCPLL	VCCI	VJTAG	VPUMP
Flash*Freeze	On	On	On	On	On/off/floating
Sleep	Off	Off	On	Off	Off
Shutdown	Off	Off	Off	Off	Off
No Flash*Freeze	On	On	On	On	On/off/floating

Note: Off: Power Supply level = 0 V

Table 2-9 • Quiescent Supply Current (I_{DD}) Characteristics, IGLOO nano Flash*Freeze Mode*

	Core Voltage	AGLN010	AGLN015	AGLN020	AGLN060	AGLN125	AGLN250	Units
Typical (25°C)	1.2 V	1.9	3.3	3.3	8	13	20	μA
	1.5 V	5.8	6	6	10	18	34	μA

Note: * I_{DD} includes VCC, VPUMP, VCCI, VCCPLL, and VMV currents. Values do not include I/O static contribution, which is shown in Table 2-13 on page 2-9 through Table 2-14 on page 2-9 and Table 2-15 on page 2-10 through Table 2-18 on page 2-11 (PDC6 and PDC7).

Overview of I/O Performance

Summary of I/O DC Input and Output Levels – Default I/O Software Settings

Table 2-21 • Summary of Maximum and Minimum DC Input and Output Levels
Applicable to Commercial and Industrial Conditions—Software Default Settings

I/O Standard	Drive Strength	Equivalent Software Default Drive Strength ²	Slew Rate	VIL		VIH		VOL	VOH	IOL ¹	IOH ¹
				Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA
3.3 V LVTTTL / 3.3 V LVCMOS	8 mA	8 mA	High	–0.3	0.8	2	3.6	0.4	2.4	8	8
3.3 V LVCMOS Wide Range ³	100 μ A	8 mA	High	–0.3	0.8	2	3.6	0.2	VCCI – 0.2	100 μ A	100 μ A
2.5 V LVCMOS	8 mA	8 mA	High	–0.3	0.7	1.7	3.6	0.7	1.7	8	8
1.8 V LVCMOS	4 mA	4 mA	High	–0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI – 0.45	4	4
1.5 V LVCMOS	2 mA	2 mA	High	–0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.25 * VCCI	0.75 * VCCI	2	2
1.2 V LVCMOS ⁴	1 mA	1 mA	High	–0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.25 * VCCI	0.75 * VCCI	1	1
1.2 V LVCMOS Wide Range ^{4,5}	100 μ A	1 mA	High	–0.3	0.3 * VCCI	0.7 * VCCI	3.6	0.1	VCCI – 0.1	100 μ A	100 μ A

Notes:

1. Currents are measured at 85°C junction temperature.
2. The minimum drive strength for any LVCMOS 1.2 V or LVCMOS 3.3 V software configuration when run in wide range is $\pm 100 \mu$ A. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.
3. All LVCMOS 3.3 V software macros support LVCMOS 3.3 V wide range, as specified in the JESD8-B specification.
4. Applicable to IGLOO nano V2 devices operating at VCCI $\geq$ VCC.
5. All LVCMOS 1.2 V software macros support LVCMOS 1.2 V wide range, as specified in the JESD8-12 specification.

Table 2-22 • Summary of Maximum and Minimum DC Input Levels
Applicable to Commercial and Industrial Conditions

DC I/O Standards	Commercial ¹		Industrial ²	
	IIL ³	IIH ⁴	IIL ³	IIH ⁴
	μ A	μ A	μ A	μ A
3.3 V LVTTTL / 3.3 V LVCMOS	10	10	15	15
3.3 V LVCOMS Wide Range	10	10	15	15
2.5 V LVCMOS	10	10	15	15
1.8 V LVCMOS	10	10	15	15
1.5 V LVCMOS	10	10	15	15
1.2 V LVCMOS ⁵	10	10	15	15
1.2 V LVCMOS Wide Range ⁵	10	10	15	15

Notes:

1. Commercial range ($-20^{\circ}\text{C} < T_A < 70^{\circ}\text{C}$)
2. Industrial range ($-40^{\circ}\text{C} < T_A < 85^{\circ}\text{C}$)
3. I_{IH} is the input leakage current per I/O pin over recommended operating conditions, where $V_{IH} < V_{IN} < V_{CCI}$. Input current is larger when operating outside recommended ranges.
4. I_{IL} is the input leakage current per I/O pin over recommended operating conditions, where $-0.3 \text{ V} < V_{IN} < V_{IL}$.
5. Applicable to IGLOO nano V2 devices operating at VCCI $\geq$ VCC.

Applies to IGLOO nano at 1.2 V Core Operating Conditions

Table 2-26 • Summary of I/O Timing Characteristics—Software Default Settings
STD Speed Grade, Commercial-Case Conditions: $T_J = 70^\circ\text{C}$, Worst-Case $V_{CC} = 1.14\text{ V}$,
Worst-Case $V_{CCI} = 3.0\text{ V}$

I/O Standard	Drive Strength (mA)	Equiv. Software Default Drive Strength Option ¹	Slew Rate	Capacitive Load (pF)	t_{DOUT}	t_{DP}	t_{DIN}	t_{PY}	t_{PYS}	t_{EOUT}	t_{ZL}	t_{ZH}	t_{LZ}	t_{HZ}	Units
3.3 V LVTTTL / 3.3 V LVCMOS	8 mA	8 mA	High	5 pF	1.55	2.31	0.26	0.97	1.36	1.10	2.34	1.90	2.43	3.14	ns
3.3 V LVCMOS Wide Range ²	100 μA	8 mA	High	5 pF	1.55	3.25	0.26	1.31	1.91	1.10	3.25	2.61	3.38	4.27	ns
2.5 V LVCMOS	8 mA	8 mA	High	5 pF	1.55	2.30	0.26	1.21	1.39	1.10	2.33	2.04	2.41	2.99	ns
1.8 V LVCMOS	4 mA	4 mA	High	5 pF	1.55	2.49	0.26	1.13	1.59	1.10	2.53	2.34	2.42	2.81	ns
1.5 V LVCMOS	2 mA	2 mA	High	5 pF	1.55	2.78	0.26	1.27	1.77	1.10	2.82	2.62	2.44	2.74	ns
1.2 V LVCMOS	1 mA	1 mA	High	5 pF	1.55	3.50	0.26	1.56	2.27	1.10	3.37	3.10	2.55	2.66	ns
1.2 V LVCMOS Wide Range ³	100 μA	1 mA	High	5 pF	1.55	3.50	0.26	1.56	2.27	1.10	3.37	3.10	2.55	2.66	ns

Notes:

1. The minimum drive strength for any LVCMOS 1.2 V or LVCMOS 3.3 V software configuration when run in wide range is $\pm 100\text{ }\mu\text{A}$. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.
2. All LVCMOS 3.3 V software macros support LVCMOS 3.3 V wide range, as specified in the JESD8-B specification.
3. All LVCMOS 1.2 V software macros support LVCMOS 1.2 V side range as specified in the JESD8-12 specification.
4. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Table 2-29 • I/O Weak Pull-Up/Pull-Down Resistances
Minimum and Maximum Weak Pull-Up/Pull-Down Resistance Values

VCCI	$R_{(WEAK\ PULL-UP)}^1 (\Omega)$		$R_{(WEAK\ PULL-DOWN)}^2 (\Omega)$	
	Min.	Max.	Min.	Max.
3.3 V	10 K	45 K	10 K	45 K
3.3 V (wide range I/Os)	10 K	45 K	10 K	45 K
2.5 V	11 K	55 K	12 K	74 K
1.8 V	18 K	70 K	17 K	110 K
1.5 V	19 K	90 K	19 K	140 K
1.2 V	25 K	110 K	25 K	150 K
1.2 V (wide range I/Os)	19 K	110 K	19 K	150 K

Notes:

1. $R_{(WEAK\ PULL-UP-MAX)} = (VCCI_{max} - VOH_{spec}) / I_{(WEAK\ PULL-UP-MIN)}$
2. $R_{(WEAK\ PULL-DOWN-MAX)} = (VOL_{spec}) / I_{(WEAK\ PULL-DOWN-MIN)}$

Table 2-30 • I/O Short Currents IOSH/IOSL

	Drive Strength	IOSL (mA)*	IOSH (mA)*
3.3 V LVTTTL / 3.3 V LVCMOS	2 mA	25	27
	4 mA	25	27
	6 mA	51	54
	8 mA	51	54
3.3 V LVCMOS Wide Range	100 μ A	Same as equivalent software default drive	
2.5 V LVCMOS	2 mA	16	18
	4 mA	16	18
	6 mA	32	37
	8 mA	32	37
1.8 V LVCMOS	2 mA	9	11
	4 mA	17	22
1.5 V LVCMOS	2 mA	13	16
1.2 V LVCMOS	1 mA	10	13
1.2 V LVCMOS Wide Range	100 μ A	10	13

Note: * $T_J = 100^\circ\text{C}$

Applies to 1.2 V DC Core Voltage

Table 2-43 • 3.3 V LVC MOS Wide Range Low Slew – Applies to 1.2 V DC Core Voltage
Commercial-Case Conditions: $T_J = 70^\circ\text{C}$, Worst-Case $V_{CC} = 1.14\text{ V}$, Worst-Case $V_{CCI} = 2.7\text{ V}$

Drive Strength	Equivalent Software Default Drive Strength Option ¹	Speed Grade	t_{DOUT}	t_{DP}	t_{DIN}	t_{PY}	t_{PYS}	t_{EOUT}	t_{ZL}	t_{ZH}	t_{LZ}	t_{HZ}	Units
100 μA	2 mA	STD	1.55	6.01	0.26	1.31	1.91	1.10	6.01	5.66	3.02	3.49	ns
100 μA	4 mA	STD	1.55	6.01	0.26	1.31	1.91	1.10	6.01	5.66	3.02	3.49	ns
100 μA	6 mA	STD	1.55	5.02	0.26	1.31	1.91	1.10	5.02	4.76	3.38	4.10	ns
100 μA	8 mA	STD	1.55	5.02	0.26	1.31	1.91	1.10	5.02	4.76	3.38	4.10	ns

Notes:

1. The minimum drive strength for any LVC MOS 3.3 V software configuration when run in wide range is $\pm 100\text{ }\mu\text{A}$. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.
2. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Table 2-44 • 3.3 V LVC MOS Wide Range High Slew – Applies to 1.2 V DC Core Voltage
Commercial-Case Conditions: $T_J = 70^\circ\text{C}$, Worst-Case $V_{CC} = 1.14\text{ V}$, Worst-Case $V_{CCI} = 2.7\text{ V}$

Drive Strength	Equivalent Software Default Drive Strength Option ¹	Speed Grade	t_{DOUT}	t_{DP}	t_{DIN}	t_{PY}	t_{PYS}	t_{EOUT}	t_{ZL}	t_{ZH}	t_{LZ}	t_{HZ}	Units
100 μA	2 mA	STD	1.55	3.82	0.26	1.31	1.91	1.10	3.82	3.15	3.01	3.65	ns
100 μA	4 mA	STD	1.55	3.82	0.26	1.31	1.91	1.10	3.82	3.15	3.01	3.65	ns
100 μA	6 mA	STD	1.55	3.25	0.26	1.31	1.91	1.10	3.25	2.61	3.38	4.27	ns
100 μA	8 mA	STD	1.55	3.25	0.26	1.31	1.91	1.10	3.25	2.61	3.38	4.27	ns

Notes:

1. The minimum drive strength for any LVC MOS 3.3 V software configuration when run in wide range is $\pm 100\text{ }\mu\text{A}$. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.
2. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.
3. Software default selection highlighted in gray.

1.2 V DC Core Voltage

Table 2-77 • Output Enable Register Propagation Delays
Commercial-Case Conditions: $T_J = 70^{\circ}\text{C}$, Worst-Case $V_{CC} = 1.14\text{ V}$

Parameter	Description	Std.	Units
t_{OECLKQ}	Clock-to-Q of the Output Enable Register	1.10	ns
t_{OESUD}	Data Setup Time for the Output Enable Register	1.15	ns
t_{OEHD}	Data Hold Time for the Output Enable Register	0.00	ns
$t_{OECLR2Q}$	Asynchronous Clear-to-Q of the Output Enable Register	1.65	ns
$t_{OEPRE2Q}$	Asynchronous Preset-to-Q of the Output Enable Register	1.65	ns
$t_{OEREMCLR}$	Asynchronous Clear Removal Time for the Output Enable Register	0.00	ns
$t_{OERECCLR}$	Asynchronous Clear Recovery Time for the Output Enable Register	0.24	ns
$t_{OEREMPRE}$	Asynchronous Preset Removal Time for the Output Enable Register	0.00	ns
$t_{OERECPRE}$	Asynchronous Preset Recovery Time for the Output Enable Register	0.24	ns
$t_{OEWCCLR}$	Asynchronous Clear Minimum Pulse Width for the Output Enable Register	0.19	ns
t_{OEWPPE}	Asynchronous Preset Minimum Pulse Width for the Output Enable Register	0.19	ns
$t_{OECKMPWH}$	Clock Minimum Pulse Width HIGH for the Output Enable Register	0.31	ns
$t_{OECKMPWL}$	Clock Minimum Pulse Width LOW for the Output Enable Register	0.28	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-7 for derating values.

DDR Module Specifications

Note: DDR is not supported for AGLN010, AGLN015, and AGLN020 devices.

Input DDR Module

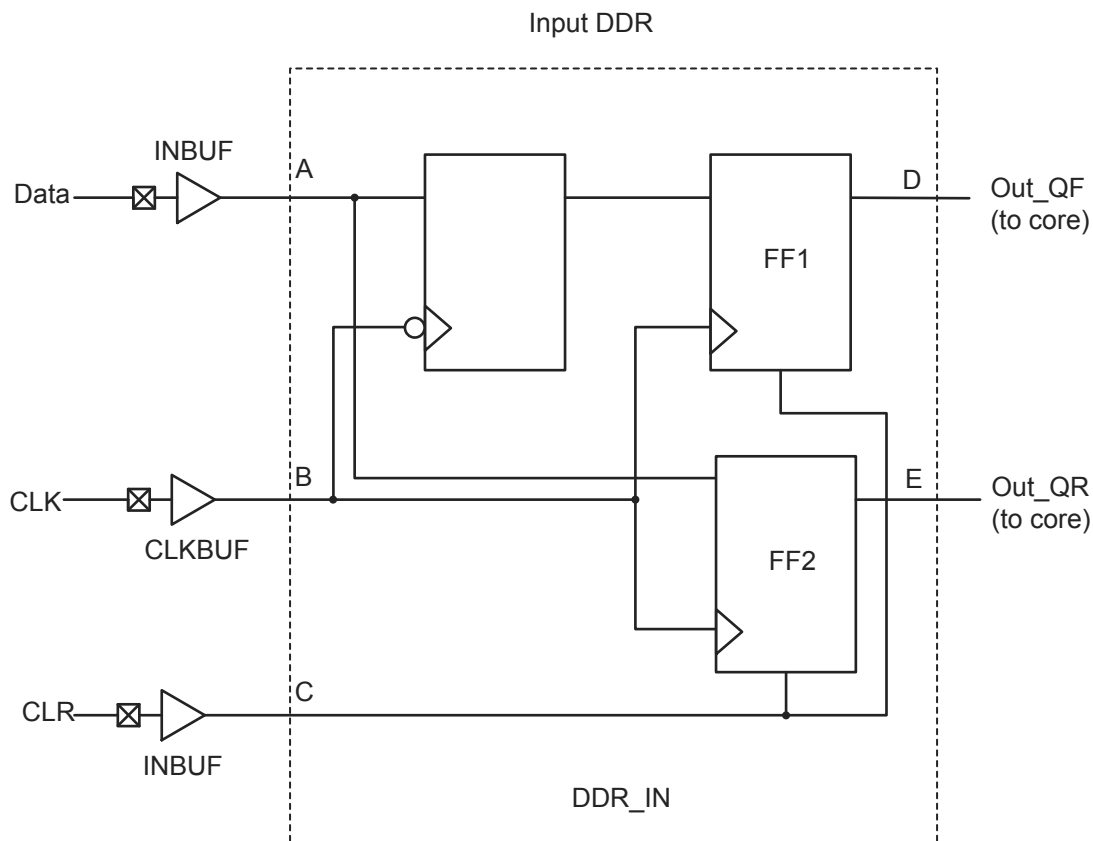


Figure 2-17 • Input DDR Timing Model

Table 2-78 • Parameter Definitions

Parameter Name	Parameter Definition	Measuring Nodes (from, to)
t_{DDRICKQ1}	Clock-to-Out Out_QR	B, D
t_{DDRICKQ2}	Clock-to-Out Out_QF	B, E
t_{DDRISUD}	Data Setup Time of DDR input	A, B
t_{DDRIHD}	Data Hold Time of DDR input	A, B
$t_{\text{DDRICLR2Q1}}$	Clear-to-Out Out_QR	C, D
$t_{\text{DDRICLR2Q2}}$	Clear-to-Out Out_QF	C, E
$t_{\text{DDRIREMCLR}}$	Clear Removal	C, B
$t_{\text{DDRIRECCLR}}$	Clear Recovery	C, B

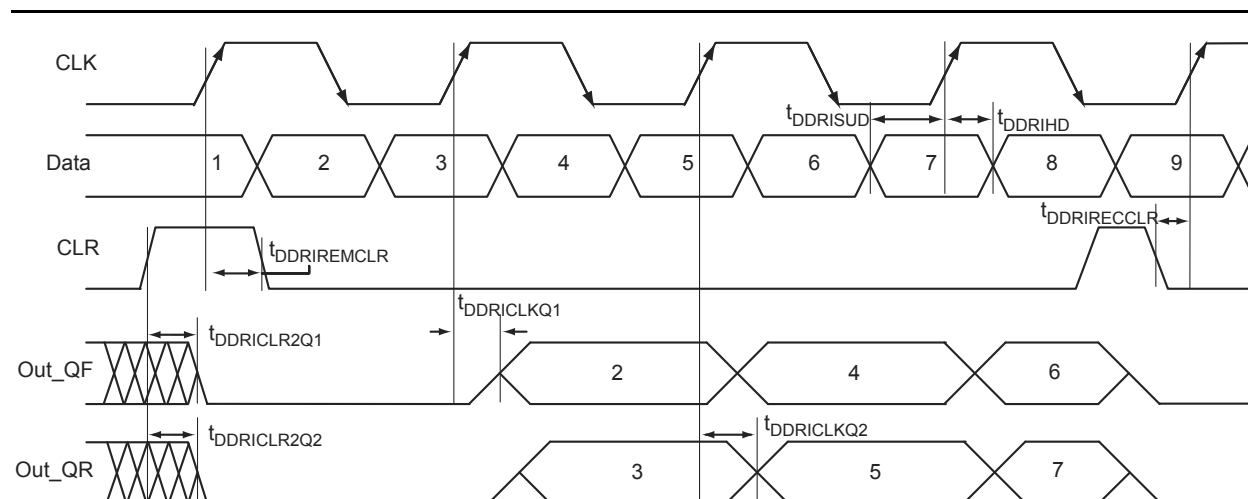


Figure 2-18 • Input DDR Timing Diagram

Timing Characteristics

1.5 V DC Core Voltage

Table 2-79 • Input DDR Propagation Delays

Commercial-Case Conditions: $T_J = 70^\circ\text{C}$, Worst-Case $V_{CC} = 1.25\text{ V}$

Parameter	Description	Std.	Units
t_{DDRCLKQ1}	Clock-to-Out Out_QR for Input DDR	0.48	ns
t_{DDRCLKQ2}	Clock-to-Out Out_QF for Input DDR	0.65	ns
t_{DDRISUD1}	Data Setup for Input DDR (negedge)	0.50	ns
t_{DDRISUD2}	Data Setup for Input DDR (posedge)	0.40	ns
t_{DDRHD1}	Data Hold for Input DDR (negedge)	0.00	ns
t_{DDRHD2}	Data Hold for Input DDR (posedge)	0.00	ns
$t_{\text{DDRCLR2Q1}}$	Asynchronous Clear-to-Out Out_QR for Input DDR	0.82	ns
$t_{\text{DDRCLR2Q2}}$	Asynchronous Clear-to-Out Out_QF for Input DDR	0.98	ns
$t_{\text{DDRREMCLR}}$	Asynchronous Clear Removal Time for Input DDR	0.00	ns
$t_{\text{DDRRECCLR}}$	Asynchronous Clear Recovery Time for Input DDR	0.23	ns
t_{DDRWCCLR}	Asynchronous Clear Minimum Pulse Width for Input DDR	0.19	ns
$t_{\text{DDRICKMPWH}}$	Clock Minimum Pulse Width HIGH for Input DDR	0.31	ns
$t_{\text{DDRICKMPWL}}$	Clock Minimum Pulse Width LOW for Input DDR	0.28	ns
F_{DDRIMAX}	Maximum Frequency for Input DDR	250.00	MHz

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-7 for derating values.

1.2 V DC Core Voltage

Table 2-80 • Input DDR Propagation Delays
Commercial-Case Conditions: $T_J = 70^\circ\text{C}$, Worst-Case $V_{CC} = 1.14\text{ V}$

Parameter	Description	Std.	Units
t_{DDRICKQ1}	Clock-to-Out Out_QR for Input DDR	0.76	ns
t_{DDRICKQ2}	Clock-to-Out Out_QF for Input DDR	0.94	ns
t_{DDRISUD1}	Data Setup for Input DDR (negedge)	0.93	ns
t_{DDRISUD2}	Data Setup for Input DDR (posedge)	0.84	ns
t_{DDRILD1}	Data Hold for Input DDR (negedge)	0.00	ns
t_{DDRILD2}	Data Hold for Input DDR (posedge)	0.00	ns
$t_{\text{DDRICLR2Q1}}$	Asynchronous Clear-to-Out Out_QR for Input DDR	1.23	ns
$t_{\text{DDRICLR2Q2}}$	Asynchronous Clear-to-Out Out_QF for Input DDR	1.42	ns
$t_{\text{DDRIREMCLR}}$	Asynchronous Clear Removal Time for Input DDR	0.00	ns
$t_{\text{DDRIRECCLR}}$	Asynchronous Clear Recovery Time for Input DDR	0.24	ns
t_{DDRWCCLR}	Asynchronous Clear Minimum Pulse Width for Input DDR	0.19	ns
$t_{\text{DDRICKMPWH}}$	Clock Minimum Pulse Width HIGH for Input DDR	0.31	ns
$t_{\text{DDRICKMPWL}}$	Clock Minimum Pulse Width LOW for Input DDR	0.28	ns
F_{DDRIMAX}	Maximum Frequency for Input DDR	160.00	MHz

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-7 for derating values.

Table 2-105 • RAM512X18

Commercial-Case Conditions: $T_J = 70^\circ\text{C}$, Worst-Case $V_{CC} = 1.14\text{ V}$

Parameter	Description	Std.	Units
t_{AS}	Address setup time	1.28	ns
t_{AH}	Address hold time	0.25	ns
t_{ENS}	REN, WEN setup time	1.13	ns
t_{ENH}	REN, WEN hold time	0.13	ns
t_{DS}	Input data (WD) setup time	1.10	ns
t_{DH}	Input data (WD) hold time	0.55	ns
t_{CKQ1}	Clock High to new data valid on RD (output retained)	6.56	ns
t_{CKQ2}	Clock High to new data valid on RD (pipelined)	2.67	ns
t_{C2CRWH}^1	Address collision clk-to-clk delay for reliable read access after write on same address; applicable to opening edge	0.87	ns
t_{C2CWRH}^1	Address collision clk-to-clk delay for reliable write access after read on same address; applicable to opening edge	1.04	ns
t_{RSTBQ}	RESET LOW to data out LOW on RD (flow through)	3.21	ns
	RESET LOW to data out LOW on RD (pipelined)	3.21	ns
$t_{REMRSTB}$	RESET removal	0.93	ns
$t_{RECRSTB}$	RESET recovery	4.94	ns
$t_{MPWRSTB}$	RESET minimum pulse width	1.18	ns
t_{CYC}	Clock cycle time	10.90	ns
F_{MAX}	Maximum frequency	92	MHz

Notes:

1. For more information, refer to the application note AC374: Simultaneous Read-Write Operations in Dual-Port SRAM for Flash-Based FPGAs and SoC FPGAs App Note.
2. For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-7 for derating values.

1.2 V DC Core Voltage

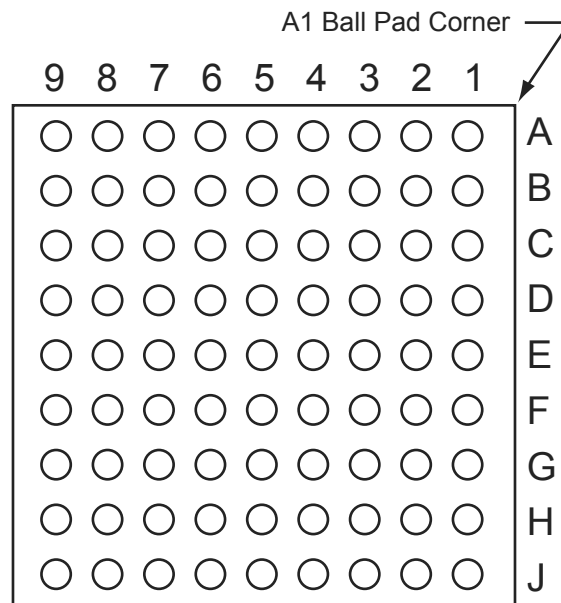
Table 2-107 • FIFO

Worst Commercial-Case Conditions: $T_J = 70^\circ\text{C}$, $V_{CC} = 1.14\text{ V}$

Parameter	Description	Std.	Units
t_{ENS}	REN, WEN Setup Time	3.44	ns
t_{ENH}	REN, WEN Hold Time	0.26	ns
t_{BKS}	BLK Setup Time	0.30	ns
t_{BKH}	BLK Hold Time	0.00	ns
t_{DS}	Input Data (DI) Setup Time	1.30	ns
t_{DH}	Input Data (DI) Hold Time	0.41	ns
t_{CKQ1}	Clock High to New Data Valid on RD (flow-through)	5.67	ns
t_{CKQ2}	Clock High to New Data Valid on RD (pipelined)	3.02	ns
t_{RCKEF}	RCLK High to Empty Flag Valid	6.02	ns
t_{WCKFF}	WCLK High to Full Flag Valid	5.71	ns
t_{CKAF}	Clock High to Almost Empty/Full Flag Valid	22.17	ns
t_{RSTFG}	RESET LOW to Empty/Full Flag Valid	5.93	ns
t_{RSTAF}	RESET LOW to Almost Empty/Full Flag Valid	21.94	ns
t_{RSTBQ}	RESET LOW to Data Out Low on RD (flow-through)	3.41	ns
	RESET LOW to Data Out Low on RD (pipelined)	4.09	3.41
t_{REMRSTB}	RESET Removal	1.02	ns
t_{RECRSTB}	RESET Recovery	5.48	ns
t_{MPWRSTB}	RESET Minimum Pulse Width	1.18	ns
t_{CYC}	Clock Cycle Time	10.90	ns
F_{MAX}	Maximum Frequency for FIFO	92	MHz

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-7 for derating values.

UC81



Note: This is the bottom view of the package.

Note

For Package Manufacturing and Environmental information, visit the Resource Center at <http://www.microsemi.com/soc/products/solutions/package/docs.aspx>.

UC81	
Pin Number	AGLN020 Function
A1	IO64RSB2
A2	IO54RSB2
A3	IO57RSB2
A4	IO36RSB1
A5	IO32RSB1
A6	IO24RSB1
A7	IO20RSB1
A8	IO04RSB0
A9	IO08RSB0
B1	IO59RSB2
B2	IO55RSB2
B3	IO62RSB2
B4	IO34RSB1
B5	IO28RSB1
B6	IO22RSB1
B7	IO18RSB1
B8	IO00RSB0
B9	IO03RSB0
C1	IO51RSB2
C2	IO50RSB2
C3	NC
C4	NC
C5	NC
C6	NC
C7	NC
C8	IO10RSB0
C9	IO07RSB0
D1	IO49RSB2
D2	IO44RSB2
D3	NC
D4	VCC
D5	VCCIB2
D6	GND
D7	NC
D8	IO13RSB0
D9	IO12RSB0

UC81	
Pin Number	AGLN020 Function
E1	GEC0/IO48RSB2
E2	GEA0/IO47RSB2
E3	NC
E4	VCCIB1
E5	VCC
E6	VCCIB0
E7	NC
E8	GDA0/IO15RSB0
E9	GDC0/IO14RSB0
F1	IO46RSB2
F2	IO45RSB2
F3	NC
F4	GND
F5	VCCIB1
F6	NC
F7	NC
F8	IO16RSB0
F9	IO17RSB0
G1	IO43RSB2
G2	IO42RSB2
G3	IO41RSB2
G4	IO31RSB1
G5	NC
G6	IO21RSB1
G7	NC
G8	VJTAG
G9	TRST
H1	IO40RSB2
H2	FF/IO39RSB1
H3	IO35RSB1
H4	IO29RSB1
H5	IO26RSB1
H6	IO25RSB1
H7	IO19RSB1
H8	TDI
H9	TDO

UC81	
Pin Number	AGLN020 Function
J1	IO38RSB1
J2	IO37RSB1
J3	IO33RSB1
J4	IO30RSB1
J5	IO27RSB1
J6	IO23RSB1
J7	TCK
J8	TMS
J9	VPUMP

CS81	
Pin Number	AGLN125Z Function
A1	GAA0/IO00RSB0
A2	GAA1/IO01RSB0
A3	GAC0/IO04RSB0
A4	IO13RSB0
A5	IO22RSB0
A6	IO32RSB0
A7	GBB0/IO37RSB0
A8	GBA1/IO40RSB0
A9	GBA2/IO41RSB0
B1	GAA2/IO132RSB1
B2	GAB0/IO02RSB0
B3	GAC1/IO05RSB0
B4	IO11RSB0
B5	IO25RSB0
B6	GBC0/IO35RSB0
B7	GBB1/IO38RSB0
B8	IO42RSB0
B9	GBB2/IO43RSB0
C1	GAB2/IO130RSB1
C2	IO131RSB1
C3	GND
C4	IO15RSB0
C5	IO28RSB0
C6	GND
C7	GBA0/IO39RSB0
C8	GBC2/IO45RSB0
C9	IO47RSB0
D1	GAC2/IO128RSB1
D2	IO129RSB1
D3	GFA2/IO117RSB1
D4	VCC
D5	VCCIB0
D6	GND
D7	GCC2/IO59RSB0
D8	GCC1/IO51RSB0
D9	GCC0/IO52RSB0

CS81	
Pin Number	AGLN125Z Function
E1	GFB0/IO120RSB1
E2	GFB1/IO121RSB1
E3	GFA1/IO118RSB1
E4	VCCIB1
E5	VCC
E6	VCCIB0
E7	GCA0/IO56RSB0
E8	GCA1/IO55RSB0
E9	GCB2/IO58RSB0
F1*	VCCPLF
F2*	VCOMPLF
F3	GND
F4	GND
F5	VCCIB1
F6	GND
F7	GDA1/IO65RSB0
F8	GDC1/IO61RSB0
F9	GDC0/IO62RSB0
G1	GEA0/IO104RSB1
G2	GEC0/IO108RSB1
G3	GEB1/IO107RSB1
G4	IO96RSB1
G5	IO92RSB1
G6	IO72RSB1
G7	GDB2/IO68RSB1
G8	VJTAG
G9	TRST
H1	GEA1/IO105RSB1
H2	FF/GEB2/IO102RSB1
H3	IO99RSB1
H4	IO94RSB1
H5	IO91RSB1
H6	IO81RSB1
H7	GDA2/IO67RSB1
H8	TDI
H9	TDO

CS81	
Pin Number	AGLN125Z Function
J1	GEA2/IO103RSB1
J2	GEC2/IO101RSB1
J3	IO97RSB1
J4	IO93RSB1
J5	IO90RSB1
J6	IO78RSB1
J7	TCK
J8	TMS
J9	VPUMP

Note: * Pin numbers F1 and F2 must be connected to ground because a PLL is not supported for AGLN125Z-CS81.

QN68	
Pin Number	AGLN015 Function
1	IO60RSB2
2	IO54RSB2
3	IO52RSB2
4	IO50RSB2
5	IO49RSB2
6	GEC0/IO48RSB2
7	GEA0/IO47RSB2
8	VCC
9	GND
10	VCCIB2
11	IO46RSB2
12	IO45RSB2
13	IO44RSB2
14	IO43RSB2
15	IO42RSB2
16	IO41RSB2
17	IO40RSB2
18	FF/IO39RSB1
19	IO37RSB1
20	IO35RSB1
21	IO33RSB1
22	IO31RSB1
23	IO30RSB1
24	VCC
25	GND
26	VCCIB1
27	IO27RSB1
28	IO25RSB1
29	IO23RSB1
30	IO21RSB1
31	IO19RSB1
32	TCK
33	TDI
34	TMS
35	VPUMP

QN68	
Pin Number	AGLN015 Function
36	TDO
37	TRST
38	VJTAG
39	IO17RSB0
40	IO16RSB0
41	GDA0/IO15RSB0
42	GDC0/IO14RSB0
43	IO13RSB0
44	VCCIB0
45	GND
46	VCC
47	IO12RSB0
48	IO11RSB0
49	IO09RSB0
50	IO05RSB0
51	IO00RSB0
52	IO07RSB0
53	IO03RSB0
54	IO18RSB1
55	IO20RSB1
56	IO22RSB1
57	IO24RSB1
58	IO28RSB1
59	NC
60	GND
61	NC
62	IO32RSB1
63	IO34RSB1
64	IO36RSB1
65	IO61RSB2
66	IO58RSB2
67	IO56RSB2
68	IO63RSB2

QN68		QN68	
Pin Number	AGLN030Z Function	Pin Number	AGLN030Z Function
1	IO82RSB1	36	TDO
2	IO80RSB1	37	TRST
3	IO78RSB1	38	VJTAG
4	IO76RSB1	39	IO40RSB0
5	GEC0/IO73RSB1	40	IO37RSB0
6	GEA0/IO72RSB1	41	GDB0/IO34RSB0
7	GEB0/IO71RSB1	42	GDA0/IO33RSB0
8	VCC	43	GDC0/IO32RSB0
9	GND	44	VCCIB0
10	VCCIB1	45	GND
11	IO68RSB1	46	VCC
12	IO67RSB1	47	IO31RSB0
13	IO66RSB1	48	IO29RSB0
14	IO65RSB1	49	IO28RSB0
15	IO64RSB1	50	IO27RSB0
16	IO63RSB1	51	IO25RSB0
17	IO62RSB1	52	IO24RSB0
18	FF/IO60RSB1	53	IO22RSB0
19	IO58RSB1	54	IO21RSB0
20	IO56RSB1	55	IO19RSB0
21	IO54RSB1	56	IO17RSB0
22	IO52RSB1	57	IO15RSB0
23	IO51RSB1	58	IO14RSB0
24	VCC	59	VCCIB0
25	GND	60	GND
26	VCCIB1	61	VCC
27	IO50RSB1	62	IO12RSB0
28	IO48RSB1	63	IO10RSB0
29	IO46RSB1	64	IO08RSB0
30	IO44RSB1	65	IO06RSB0
31	IO42RSB1	66	IO04RSB0
32	TCK	67	IO02RSB0
33	TDI	68	IO00RSB0
34	TMS		
35	VPUMP		

VQ100	
Pin Number	AGLN060 Function
1	GND
2	GAA2/IO51RSB1
3	IO52RSB1
4	GAB2/IO53RSB1
5	IO95RSB1
6	GAC2/IO94RSB1
7	IO93RSB1
8	IO92RSB1
9	GND
10	GFB1/IO87RSB1
11	GFB0/IO86RSB1
12	VCOMPLF
13	GFA0/IO85RSB1
14	VCCPLF
15	GFA1/IO84RSB1
16	GFA2/IO83RSB1
17	VCC
18	VCCIB1
19	GEC1/IO77RSB1
20	GEB1/IO75RSB1
21	GEB0/IO74RSB1
22	GEA1/IO73RSB1
23	GEA0/IO72RSB1
24	VMV1
25	GNDQ
26	GEA2/IO71RSB1
27	FF/GEB2/IO70RSB1
28	GEC2/IO69RSB1
29	IO68RSB1
30	IO67RSB1
31	IO66RSB1
32	IO65RSB1
33	IO64RSB1
34	IO63RSB1
35	IO62RSB1

VQ100	
Pin Number	AGLN060 Function
36	IO61RSB1
37	VCC
38	GND
39	VCCIB1
40	IO60RSB1
41	IO59RSB1
42	IO58RSB1
43	IO57RSB1
44	GDC2/IO56RSB1
45*	GDB2/IO55RSB1
46	GDA2/IO54RSB1
47	TCK
48	TDI
49	TMS
50	VMV1
51	GND
52	VPUMP
53	NC
54	TDO
55	TRST
56	VJTAG
57	GDA1/IO49RSB0
58	GDC0/IO46RSB0
59	GDC1/IO45RSB0
60	GCC2/IO43RSB0
61	GCB2/IO42RSB0
62	GCA0/IO40RSB0
63	GCA1/IO39RSB0
64	GCC0/IO36RSB0
65	GCC1/IO35RSB0
66	VCCIB0
67	GND
68	VCC
69	IO31RSB0
70	GBC2/IO29RSB0

VQ100	
Pin Number	AGLN060 Function
71	GBB2/IO27RSB0
72	IO26RSB0
73	GBA2/IO25RSB0
74	VMV0
75	GNDQ
76	GBA1/IO24RSB0
77	GBA0/IO23RSB0
78	GBB1/IO22RSB0
79	GBB0/IO21RSB0
80	GBC1/IO20RSB0
81	GBC0/IO19RSB0
82	IO18RSB0
83	IO17RSB0
84	IO15RSB0
85	IO13RSB0
86	IO11RSB0
87	VCCIB0
88	GND
89	VCC
90	IO10RSB0
91	IO09RSB0
92	IO08RSB0
93	GAC1/IO07RSB0
94	GAC0/IO06RSB0
95	GAB1/IO05RSB0
96	GAB0/IO04RSB0
97	GAA1/IO03RSB0
98	GAA0/IO02RSB0
99	IO01RSB0
100	IO00RSB0

Note: *The bus hold attribute (hold previous I/O state in Flash*Freeze mode) is not supported for pin 45 in AGLN060-VQ100.